

# SISA96DN-T1-GE3

### **SISA96DN-T1-GE3 Information**

	Transistors - FETs, MOSFETs - SingletionMOSFET N-CH 30V 16A 1212-8	
For Reference Only	Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

## **Certified Quality**

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



## SISA96DN-T1-GE3 Specifications

Manufacturer Part Number	SISA96DN-T1-GE3
Manufacturer	Vishay Siliconix
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	PowerPAK? 1212-8
Series	TrenchFET? Gen IV
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	16A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2.2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	15nC @ 4.5V
Input Capacitance (Ciss) (Max) @ Vds	1385pF @ 15V
Vgs (Max)	+20V, -16V
FET Feature	-
Power Dissipation (Max)	26.5W (Tc)
Rds On (Max) @ Id, Vgs	8.8 mOhm @ 10A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	PowerPAK? 1212-8
Package / Case	PowerPAK? 1212-8
	Report errors?

#### SISA96DN-T1-GE3 Guarantees



Quality Guarantees

We provide 90 days warranty. \* If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



#### **Service Guarantees**

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

#### SISA96DN-T1-GE3 Payment Methods



## SISA96DN-T1-GE3 Shipping Methods



If you have any question about SISA96DN-T1-GE3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com